

PKM8721DCM-E10-F32 Module

DATASHEET

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USING THIS DOCUMENT

This document is intended for the software engineer's reference and provides detailed programming information.

Though every effort has been made to ensure that this document is current and accurate, more information may have become available subsequent to the production of this guide.



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Contents

Contact	t Us	4
Content	ts	5
1 Ma	odule Overview	6
1.1 1.2	General Description	
	odule Block Diagram	
3 Mo	odule Pin Definition	8
3.1	Module Pin Layout	8
3.2	Module Pin Description	8
3.2	P.1 Pin Description	8
3.2	2.2 Strapping Pins	9
4 RF	Characteristic	10
4.1	Wi-Fi Radio Standard	10
4.1 4.1		
4.1	· ·	
4.1	· ·	
4.1	· · ·	
4.2	Bluetooth LE Radio Standard	
4.2		
4.2	2.2 Bluetooth LE RF Receiver Specification	13
5 Mo	odule Electrical Characteristics	15
5.1	Module Operating Conditions	15
5.2	Module DC Characteristics	
	odule Schematics	
6 Mo		
6.1	Module Internal Schematics	16
7 Phy	ysical Dimensions	17
8 Pro	oduct Handling	18
8.1	Storage Conditions	12
8.2	Production Instructions	
8.3	Recommended Oven Temperature Curve	_
		20
9 Rev	vision History	20



1 Module Overview

1.1 General Description

The PKM8721DCM-E10-F32 is a multi-radio MCU module. With the open CPU architecture, customers can develop advanced applications running on the dual RISC cores. In addition, the embedded 8MB PSRAM can support running basic AI algorithms. It supports Wi-Fi 802.11 a/b/g/n wireless LAN(WLAN) network with 40MHz bandwidth and BLE 5.0 communications. The rich set of peripherals and high performance make it an ideal choice for AI toys, consumer electronics, etc.

1.2 Features

Chipset and Memory:

- RTL8721DCM chipset embedded, dual-core processor: KM4 up to 345MHz, KM0 up to 115MHz
- on-chip memory: 512KB + 160KB SRAM
- 8MB MCM PSRAM
- 16MB Flash

Wi-Fi:

- 802.11 a/b/g/n 1x1, 2.4GHz & 5GHz
- Center frequency range of operating channel: 2412MHz ~ 2484MHz, 5180MHz ~ 5825MHz
- Support 40MHz bandwidth, up to the data rate of MCS7
- Wi-Fi WEP, WPA, WPA2, WPA3, WPS; open, shared key, and pair-wise key authentication services
- Power-saving mechanism
- Channel management and co-existence

Bluetooth Low Energy:

- Bluetooth 5.0 (LE-1M/LE-2M/LE-Coded PHY (long range))
- Supports piconets in a scatter-net (up to 8 master roles and 3 slave roles)
- Supports LE data length extension
- Supports Link Layer privacy
- Supports LE advertising extensions
- Co-existence RF design between Wi-Fi and Bluetooth

Peripherals:

- 2 x I2S interface
- 4 x UART interface, baud rate up to 8Mbps within high-speed mode (40MHz)
- 2 x I2C, three speed modes: standard up to 100Kbps, fast up to 400Kbps, high to 3.4Mbps
- SDIO Device, Default speed mode (25MHz) and high-speed mode (50MHz)
- 2 x SPI, up to 50Mbps in master and slave modes, in half-duplex, full-duplex and simplex modes.
- 8 x PWM with configurable duration and duty cycle from 0 ~ 100%
- Cap touch x 4 channels
- ADC x (7+1) channels
- Programmable GPIOs
- USB 2.0 Device (Full Speed)
- IF

Antenna Option:

On-board PCB Antenna

Operating Conditions:

- Operating input voltage: (3.3 ± 10%)V
- Operating ambient temperature: -20°C to 85°C



2 Module Block Diagram

This module includes the chipset, crystal component, R/L/C components for RF matching, decoupling and RF radio antenna.

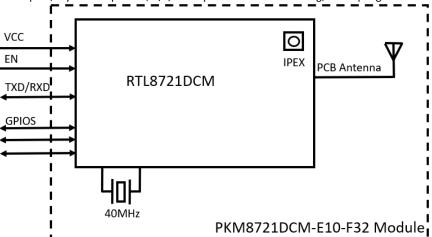


Figure 1. Block Diagram



3 Module Pin Definition

3.1 Module Pin Layout

This module has 54 pins.

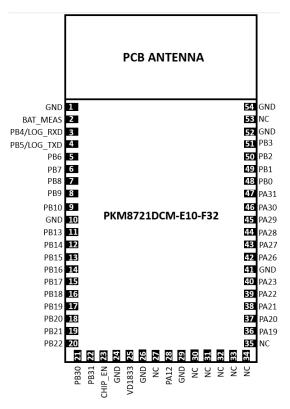


Figure 2. Module Pin Layout (Top View)

3.2 Module Pin Description

3.2.1 Pin Description

Table 1. Pin Description

Pin Name	Pin No.	Туре	Description	UART is available	I2C is available	PWM is available
GND	1	Р	Ground	NA	NA	NA
BAT_MEAS	2	1/0	BAT_MEAS	NA	NA	NA
PB4	3	1/0	UART_LOG_RXD	NA	NA	NA
PB5	4	1/0	UART_LOG_TXD	NA	NA	NA
PB6	5	1/0	GPIOB_6	√	٧	٧
PB7	6	I/O	GPIOB_7	٧	٧	٧
PB8	7	1/0	GPIOB_8	√	٧	٧
PB9	8	1/0	GPIOB_9	√	٧	٧
PB10	9	I/O	GPIOB_10	٧	٧	٧
GND	10	Р	Ground	NA	NA	NA
PB13	11	1/0	GPIOB_13	√	٧	٧
PB14	12	I/O	GPIOB_14	٧	٧	٧
PB15	13	I/O	GPIOB_15	٧	٧	٧
PB16	14	I/O	GPIOB_16	٧	٧	٧
PB17	15	1/0	GPIOB_17 / SPI1_CS	٧	٧	٧



PB18	16	I/O	GPIOB 18/SPI1 CLK	V	V	V
PB19	17	1/0	GPIOB 19 / SPI1 MOSI	V	√ V	√
PB20	18	1/0	GPIOB 20 / SPI1 MISO	V	√ V	√ V
PB21	19	1/0	GPIOB 21	V	√ V	√
PB22	20	1/0	GPIOB 22	V	V	√ V
PB30	21	1/0	GPIOB 30	V	√ V	√
PB31	22	1/0	GPIOB 31	√	√ V	√
EN	23	ı	High: Enable the chip. Low: Module power off.	NA	NA	NA
GND	24	Р	Ground	NA	NA	NA
VD1833	25	Р	Power Supply	NA	NA	NA
GND	26	Р	Ground	NA	NA	NA
NC	27	NC	NC	NA	NA	NA
PA12	28	1/0	GPIOA_12	٧	V	٧
GND	29	Р	Ground	NA	NA	NA
NC	30	NC	NC	NA	NA	NA
NC	31	NC	NC	NA	NA	NA
NC	32	NC	NC	NA	NA	NA
NC	33	NC	NC	NA	NA	NA
NC	34	NC	NC	NA	NA	NA
NC	35	NC	NC	NA	NA	NA
PA19	36	1/0	GPIOA_19	٧	٧	٧
PA20	37	1/0	GPIOA_20	٧	٧	٧
PA21	38	1/0	GPIOA_21	٧	√	٧
PA22	39	1/0	GPIOA_22	٧	٧	٧
PA23	40	1/0	GPIOA_23	٧	√	٧
GND	41	Р	Ground	NA	NA	NA
PA26	42	1/0	GPIOA_26 / D2	٧	٧	٧
PA27	43	1/0	GPIOA_27 / D3	٧	٧	٧
PA28	44	1/0	GPIOA_28 / CMD / DM	٧	٧	٧
PA29	45	1/0	GPIOA_29 / CLK / DP	٧	√	٧
PA30	46	1/0	GPIOA 30 / D0	٧	V	٧
PA31	47	1/0	GPIOA_31 / D1	٧	٧	V
PB0	48	1/0	GPIOB_0	٧	٧	√
PB1	49	1/0	GPIOB_1	٧	٧	V
PB2	50	1/0	GPIOB_2	٧	٧	√
PB3	51	1/0	GPIOB_3	٧	٧	٧
GND	52	Р	Ground	NA	NA	NA
NC	53	NC	NC	NA	NA	NA
GND	54	Р	Ground	NA	NA	NA

1 NOTE

- **P**: power supply
- I: input
- I/O: input / output
- Detail Available pin refer to "PKM8721DCM_pin_mux" table

3.2.2 Strapping Pins

This module has 2 strapping pins.

Table 2. Strapping Pin

Pin Name	Pin No.	Default State	Description
DDE	4	Dullun	1: Normal mode (default)
PB5	4	Pull up	0: Flash download mode
PB31	22	Dullium	1: Normal mode (default)
PB31	22	Pull up	0: Test mode



4 RF Characteristic

4.1 Wi-Fi Radio Standard

Table 3. Wi-Fi Radio Standard

Wi-Fi Wireless Standard	Description
Wi-Fi frequency range	 2412MHz ~ 2484MHz (2.4GHz ISM Band) 5180MHz ~ 5825MHz (5GHz)
Wi-Fi wireless standard	IEEE 802.11 a/b/g/n
Wi-Fi wireless standard Modulation	DSSS, DBPSK, DQPSK, CCK and OFDM (BPSK/QPSK/16-QAM/64-QAM)
Wi-Fi wireless data rate	 802.11a: 6/9/12/18/24/36/48/54 Mbps 802.11b: 1/2/5.5/11 Mbps 802.11g: 6/9/12/18/24/36/48/54 Mbps 802.11n: HT20 MCS0-7, HT40 MCS0-7

4.1.1 Wi-Fi 2.4GHz Band RF Transmitter Specification

Table 4. Wi-Fi 2.4GHz Transmitter Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	Center channel frequency	2412		2484	MHz
	1 Mbps DSSS		20		dBm
	11 Mbps DSSS		20		dBm
	6 Mbps OFDM		19		dBm
Output power with spectral mask	54 Mbps OFDM		19		dBm
and EVM compliance ^[1]	HT20 MCS0		19		dBm
	HT20 MCS7		19		dBm
	HT40 MCS0		19		dBm
	HT40 MCS7		18		dBm
	6 Mbps OFDM		-30	-5	dB
	54 Mbps OFDM		-34	-25	dB
Tx EVM	HT20 MCS0		-30	-5	dB
IX EVIVI	HT20 MCS7		-34	-27	dB
	HT40 MCS0		-29	-5	dB
	HT40 MCS7		-33	-27	dB
Output power variation		-1.5		1.5	dB
Carrier Suppression			-40	-30	dBc
Harmania Outnut Bayyar[2]	2nd Harmonic		-18		dBm/MHz
Harmonic Output Power ^[2]	3rd Harmonic		-22		dBm/MHz
Harris Outrout Barraria	2nd Harmonic			-50	dBm/MHz
Harmonic Output Power ^[3]	3rd Harmonic			-50	dBm/MHz

NOTE

- [1] Power level is tested after Digital Pre-Distortion (DPD) enable.
- [2] Harmonic output power is tested at IC port.
- [3] Harmonic output power is measured at RF connector with diplexer (RFDIP1606LB598D1T) and appropriate matching.

4.1.2 Wi-Fi 2.4GHz Band RF Receiver Specification

Table 5. Wi-Fi 2.4GHz Receiver Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	Center channel frequency	2412		2484	MHz
802.11b	1 Mbps DSSS		-100		dBm
Rx Sensitivity	2 Mbps DSSS		-97		dBm

Datasheet



	5.5 Mbps DSSS	-94	dBm
	11 Mbps DSSS	-90.5	dBm
	6 Mbps OFDM	-95	dBm
	9 Mbps OFDM	-93.5	dBm
	12 Mbps OFDM	-92.5	dBm
802.11g	18 Mbps OFDM	-90.5	dBm
Rx Sensitivity	24 Mbps OFDM	-87	dBm
•	36 Mbps OFDM	-84	dBm
	48 Mbps OFDM	-79.5	dBm
	54 Mbps OFDM	-78	dBm
	HT20 MCS0	-95	dBm
	HT20 MCS1	-92	dBm
	HT20 MCS2	-90	dBm
	HT20 MCS3	-87	dBm
	HT20 MCS4	-83.5	dBm
	HT20 MCS5	-79	dBm
	HT20 MCS6	-77.5	dBm
802.11n	HT20 MCS7	-76	dBm
Rx Sensitivity	HT40 MCS0	-92	dBm
	HT40 MCS1	-89	dBm
	HT40 MCS2	-87	dBm
	HT40 MCS3	-83.5	dBm
	HT40 MCS4	-80.5	dBm
	HT40 MCS5	-75.5	dBm
	HT40 MCS6	-74	dBm
	HT40 MCS7	-73	dBm
	6Mbps OFDM	0	dBm
	54Mbps OFDM	0	dBm
Maximum Bassiya Layal	HT20 MCS 0	0	dBm
Maximum Receive Level	HT20 MCS 7	0	dBm
	HT40 MCS 0	0	dBm
	HT40 MCS 7	0	dBm
	11Mbps DSSS	43	dB
	6 Mbps OFDM	44	dB
	54Mbps OFDM	26	dB
Adjacent Channel Rejection	HT20 MCS 0	43	dB
	HT20 MCS 7	23	dB
	HT40 MCS 0	32	dB
	HT40 MCS 7	14	dB

4.1.3 Wi-Fi 5GHz Band RF Transmitter Specification

Table 6. Wi-Fi 5GHz Transmitter Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	Center channel frequency	5180		5885	MHz
	6 Mbps OFDM		18		dBm
	54 Mbps OFDM		18		dBm
Output power with spectral mask	HT20 MCS0		18		dBm
and EVM compliance ^[1]	HT20 MCS7		17		dBm
	HT40 MCS0		18		dBm
	HT40 MCS7		16		dBm
	6 Mbps OFDM		-30	-5	dB
	54 Mbps OFDM		-32	-25	dB
Tx EVM	HT20 MCS0		-30	-5	dB
IX EVIVI	HT20 MCS7		-33	-27	dB
	HT40 MCS0		-30	-5	dB
	HT40 MCS7		-32	-27	dB



Output power variation		-1.5		1.5	dB
Carrier Suppression			-40	-30	dBc
Harmania autnut naugr[2]	2nd Harmonic		-28		dBm/MHz
Harmonic output power ^[2]	3rd Harmonic		-30		dBm/MHz
110	2nd Harmonic			-50	dBm/MHz
Harmonic output power ^[3]	3rd Harmonic			-50	dBm/MHz

NOTE

- [1] Power level is tested after Digital Pre-Distortion (DPD) enable.
- [2] Harmonic output power is tested at IC port.
- [3] Harmonic output power is measured at RF connector with diplexer (RFDIP1606LB598D1T) and appropriate matching.

4.1.4 Wi-Fi 5GHz Band RF Receiver Specification

Table 7. Wi-Fi 5GHz Receiver Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	Center channel frequency	5180		5885	MHz
	6 Mbps OFDM		-94.5		dBm
	9 Mbps OFDM		-92.5		dBm
	12 Mbps OFDM		-91.5		dBm
802.11a	18 Mbps OFDM		-89.5		dBm
Rx Sensitivity	24 Mbps OFDM		-86.5		dBm
	36 Mbps OFDM		-83		dBm
	48 Mbps OFDM		-78.5		dBm
	54 Mbps OFDM		-77		dBm
	HT20 MCS0		-94		dBm
	HT20 MCS1		-91.5		dBm
	HT20 MCS2		-89		dBm
	HT20 MCS3		-86		dBm
	HT20 MCS4		-82.5		dBm
	HT20 MCS5		-78		dBm
	HT20 MCS6		-76.5		dBm
802.11n	HT20 MCS7		-75		dBm
Rx Sensitivity	HT40 MCS0		-91		dBm
	HT40 MCS1		-88.5		dBm
	HT40 MCS2		-85.5		dBm
	HT40 MCS3		-82.5		dBm
	HT40 MCS4		-79		dBm
	HT40 MCS5		-74.5		dBm
	HT40 MCS6		-73		dBm
	HT40 MCS7		-71.5		dBm
	6Mbps OFDM		0		dBm
	54Mbps OFDM		0		dBm
Maximum Receive Level	HT20 MCS0		0		dBm
Maximum Receive Level	HT20 MCS7		0		dBm
	HT40 MCS0		0		dBm
	HT40 MCS7		0		dBm
	6Mbps OFDM		33		dB
	54Mbps OFDM		10		dB
Adjacent Channel Rejection	HT20 MCS0		29		dB
Aujacent Channel Rejection	HT20 MCS7		10		dB
	HT40 MCS0		29		dB
	HT40 MCS7		11		dB



4.2 Bluetooth LE Radio Standard

4.2.1 Bluetooth LE RF Transmitter Specification

Table 8. Bluetooth LE Transmitter Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	Center channel frequency	2402	2440	2480	MHz
Output Power	At max. power output level		8		dBm
Bluetooth LE 1Mbps	·				
	Frequency offset ^[1]		±10		kHz
Carrier Frequency Offset and Drift	Frequency drift		±10		kHz
	Max. drift rate		±10		kHz/50us
	Δf1 avg.		250		kHz
Modulation characteristics	Δf2 max.	185			kHz
	Δf1 avg./Δf2 avg.		0.92		
In Bond Country Engineer	±2MHz offset		-46		dBm
In-Band Spurious Emission	>±3MHz offset		-49		dBm
Bluetooth LE 2Mbps	·				
	Frequency offset ^[1]		±30		kHz
Carrier Frequency Offset and Drift	Frequency drift		±10		kHz
	Max. drift rate		±10		kHz/50us
	Δf1 avg.		500		kHz
Modulation characteristics	Δf2 max.	370			kHz
	Δf1 avg./Δf2 avg.		0.93		
	±4MHz offset		-48		dBm
In-Band Spurious Emission	±5MHz offset		-50		dBm
	>±3MHz offset		-50		dBm
Bluetooth LE 125kbps	·				
	Frequency offset ^[1]		±15		kHz
Carrier Frequency Offset and Drift	Frequency drift		±10		kHz
	Max. drift rate		±10		kHz/50us
NA advitation also restauration	Δf1 avg.		250		kHz
Modulation characteristics	Δf2 max.	185			kHz

¹ NOTE

[1] Initial carrier frequency offset should be calibrated in MP process in the customer side.

4.2.2 Bluetooth LE RF Receiver Specification

Table 9. Bluetooth LE Receiver Performance Specification

Parameter	Condition	Min.	Тур.	Max.	Unit
Frequency Range	uency Range Center channel frequency		2440	2480	MHz
Bluetooth LE 1Mbps					
Receiver Sensitivity	PER<30.8%		-99[1]		dBm
Max. Usable Signal	PER<30.8%		0		dBm
C/I co-channel (PER<30.8%)	Co-channel sensitivity		6		dB
C/I 1MHz (PER<30.8%) Adjacent channel selectivity			-5		dB
C/I 2MHz (PER<30.8%) 2nd adjacent channel selectivity			-48		dB
C/I >= 3MHz (PER<30.8%) 3rd adjacent channel selectivity			-55		dB
C/I Image Channel (PER<30.8%) Image channel selectivity			-25		dB
C/I Image 1MHz (PER<30.8%)	1MHz adjacent to image channel selectivity		-26		dB
Inter-modulation			-30		dBm
	30MHz to 2000MHz	-30			dBm
Out-of-band blocking ^[2]	2003MHz to 2399MHz	-35			dBm
	2484MHz to 2997MHz	-35			dBm



	3000MHz to 12.75GHz	-30		dBm
Bluetooth LE 2Mbps			<u> </u>	<u>.</u>
Receiver Sensitivity PER<30.8%			-95 ^[1]	dBm
Max. Usable Signal PER<30.8%			0	dBm
C/I co-channel (PER<30.8%)	Co-channel sensitivity		6	dB
C/I 2MHz (PER<30.8%)	Adjacent channel selectivity		-2	dB
C/I 4MHz (PER<30.8%)	2nd adjacent channel selectivity		-43	dB
C/I >= 6MHz (PER<30.8%)	3rd adjacent channel selectivity		-53	dB
C/I Image Channel (PER<30.8%)	Image channel selectivity		-25	dB
C/I Image 2MHz (PER<30.8%) 1MHz adjacent to image channel selectivity			-23	dB
Inter-modulation			-28	dBm
	30MHz to 2000MHz	-30		dBm
Out of board blooking[2]	2003MHz to 2399MHz	-35		dBm
Out-of-band blocking ^[2]	2484MHz to 2997MHz	-35		dBm
	3000MHz to 12.75GHz	-30		dBm
Bluetooth LE 125kbps				
Receiver Sensitivity	PER<30.8%		-106 ^[1]	dBm
C/I co-channel (PER<30.8%)	Co-channel sensitivity		3	dB
C/I 1MHz (PER<30.8%)	Adjacent channel selectivity		-15	dB
C/I 2MHz (PER<30.8%)	2nd adjacent channel selectivity		-53	dB
C/I >= 3MHz (PER<30.8%)	/I >= 3MHz (PER<30.8%) 3rd adjacent channel selectivity		-62	dB
C/I Image Channel (PER<30.8%)	Image channel selectivity		-33	dB
C/I Image 1MHz (PER<30.8%)	1MHz adjacent to image channel selectivity		-35	dB
Bluetooth LE 500kbps				
Receiver Sensitivity PER<30.8%			-101 ^[1]	dBm
C/I co-channel (PER<30.8%) Co-channel sensitivity			4	dB
C/I 1MHz (PER<30.8%)	Hz (PER<30.8%) Adjacent channel selectivity		-9	dB
C/I 2MHz (PER<30.8%)	I 2MHz (PER<30.8%) 2nd adjacent channel selectivity		-50	dB
C/I >= 3MHz (PER<30.8%) 3rd adjacent channel selectivity			-58	dB
C/I Image Channel (PER<30.8%)	Image channel selectivity		-31	dB
C/I Image 1MHz (PER<30.8%) 1MHz adjacent to image channel selectivity			-29	dB

1 NOTE

- [1] The receiver sensitivity is measured at the chip out, and channels 2440MHz and 2480MHz may have extra degradation due to spurs interference.
- [2] Frequencies where the requirements are not met are called "spurious response frequencies". The number of spurs must not exceed 10 if blocking signal power level is as specified above, and must not exceed 3 if it is reduced to -50dBm.



5 Module Electrical Characteristics

5.1 Module Operating Conditions

Table 10. Module Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Units
VCC	Power supply voltage	3.0	3.3	3.6	V
T _A	Ambient operating temperature	-20		85	°C
T _S	Storage temperature range	-65		150	°C

5.2 Module DC Characteristics

Table 11. DC Characteristic (3.3V, 25°C)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{IH}	Input-High Voltage	LVTTL	2.0			V
V _{IL}	Input-Low Voltage	LVTTL	-0.3		0.8	V
V _{OH}	Output-High Voltage	LVTTL	0.85*V _{IO}			V
V _{OL}	Output-Low Voltage	LVTTL	-		0.15*V _{IO}	V



6 Module Schematics

6.1 Module Internal Schematics

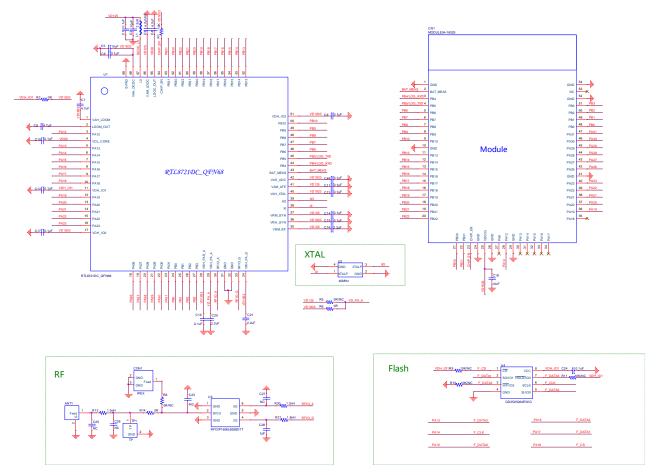


Figure 3. Module Internal Schematics



7 Physical Dimensions

Module dimension: 29 ± 0.2 mm (L) x 16 ± 0.2 mm (W) x 2.8 ± 0.1 mm (H)

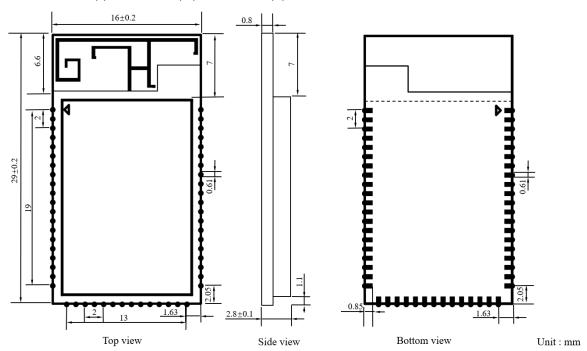


Figure 4. Module Physical Dimensions

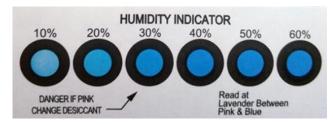


8 Product Handling

8.1 Storage Conditions

The storage conditions for a delivered module:

- Moisture sensitive level (MSL): 3
- Calculated shelf life in sealed bag: 12 months at <40°C and <90% relative humidity (RH)
- Peak package body temperature: 260°C
- A humidity indicator card (HIC) in the packaging bag.



- After bag is opened, the module that will be subjected to reflow solder or other high temperature process must be
 - Mounted within: 168 hours of factory conditions ≤30°C/60% RH, or
 - Stored per J-STD-033
- The module needs to be baked in the following cases:
 - The packaging bag is damaged before unpacking.
 - There is no humidity indicator card (HIC) in the packaging bag.
 - After unpacking, circles of 10% and above on the HIC become pink.
 - The total exposure time has lasted for over 168 hours since unpacking.
 - More than 12 months have passed since the sealing of the bag.
- If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure.

note

Level and body temperature are defined by IPC/JEDECJ-STD-020.

8.2 Production Instructions

- The PKM8721DCM-E10-F32 module can be packaged with the SMT process according to the customer's PCB designed to be SMT-packaged. After being unpacked, the module must be soldered within 24 hours. Otherwise, it needs to be put into the drying cupboard where the relative humidity is not greater than 10%; or it needs to be packaged again under vacuum and the exposure time needs to be recorded (the total exposure time cannot exceed 168 hours).
 - SMT devices needed:
 - Mounter
 - SPI
 - ◆ Reflow soldering machine
 - Thermal profiler
 - Automated optical inspection (AOI) equipment
 - Baking devices needed:
 - Cabinet oven
 - Anti-electrostatic and heat-resistant trays
 - ◆ Anti-electrostatic and heat-resistant gloves
- Baking settings:
 - Temperature: 40°C and ≤ 5% RH for reel package and 125°C and ≤5% RH for tray package (use the heat-resistant tray rather than a plastic container)
 - Time: 168 hours for reel package and 12 hours for tray package
 - Alarm temperature: 50°C for reel package and 135°C for tray package
 - Production-ready temperature after natural cooling: < 36°C
 - Re-baking situation: If a module remains unused for over 168 hours after being baked, it needs to be baked again.
 - If a batch of modules is not baked within 168 hours, do not use the wave soldering to solder them. Because these modules are Level-3 moisture-sensitive devices, they are very likely to get damp when exposed beyond the allowable time. In this case, if they are soldered at high temperatures, it may result in device failure or poor soldering.
- In the whole production process, take electrostatic discharge (ESD) protective measures.



To guarantee the passing rate, it is recommended to use the SPI and AOI to monitor the quality of solder paste printing and mounting.

8.3 Recommended Oven Temperature Curve

There are some differences between the set temperatures and the actual temperatures. All the temperatures listed in this datasheet are obtained through actual measurements.

For the SMT process, set oven temperatures according to Figure 5.

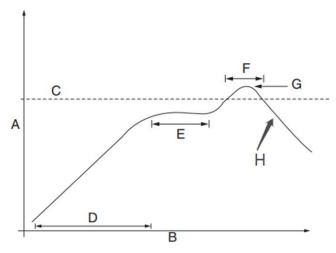


Figure 5. Reflow Soldering Curve Diagram

- D: Rising speed = (1 ~ 3)°C/s, 20°C ~ 150°C, 60s ~ 90s
- E: Average preheating temperature = 150°C ~ 200°C, 60s ~ 120s
- F: Temperature fluctuation > 217°C, 50s to 70s; peak temperature = 235°C ~ 245°C
- H: Drop speed = $(1 \sim 4)$ °C/s
- A NOTE

Adjust the balance time to ensure the rationalization treatment of gas when tin paste solves. If there are too much gaps on the PCB board, increase the balance time. Considering that the product is long placed in the welding area, to prevent components and bottom plate from damage.



9 Revision History

Data	Revision	Change Note
2025-07-03	1.0	Initial release
2025-07-18	1.1	Update RF characteristics
2025-09-25	1.2	Correct some formats